NSN 5962-01-056-4119

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Between 1.230 inches and 1.280 inches

Body Width:

Between 0.520 inches and 0.560 inches

Body Height:

Between 0.160 inches and 0.200 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Converter, signal data, type cv-3276/ash-2 (v)

Features Provided:

Hermetically sealed and monolithic and negative outputs and positive outputs and w/enable and expandable and w/buffered output and wire-or outputs and programmable and programmed and w/decoded output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

8 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

25.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

36452-116598 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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